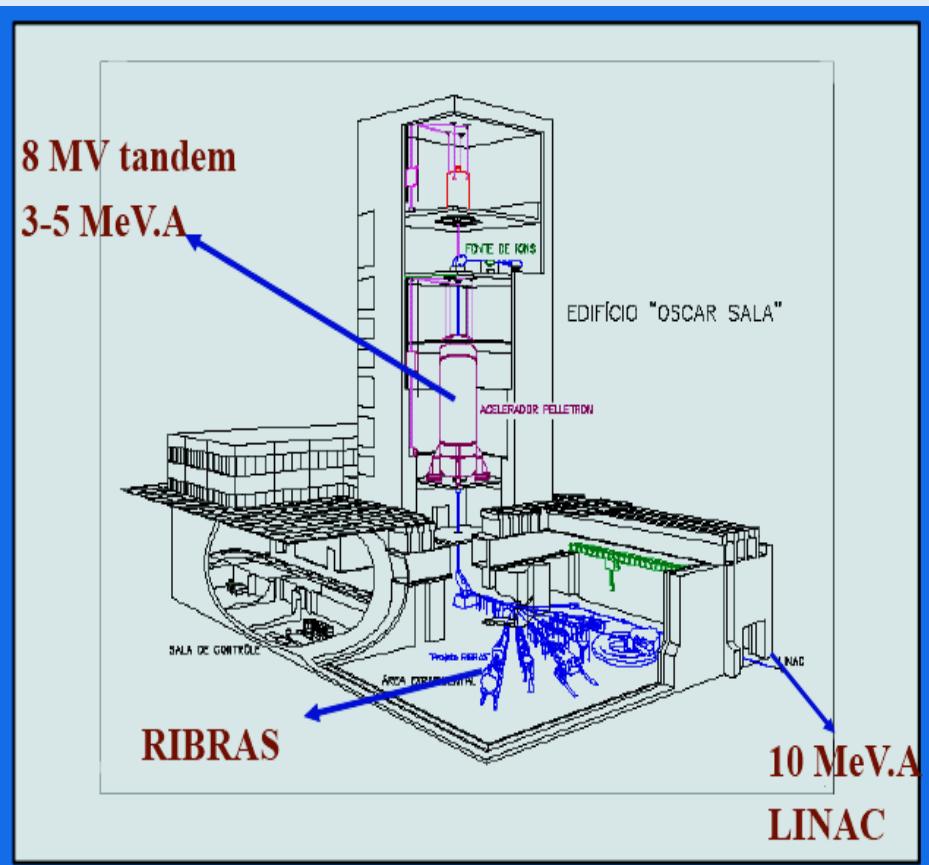


Recent results and upgrades in the Nuclear Physics Laboratory (LAFN) of the University of São Paulo



The Nuclear Physics Laboratory (LAFN) of the University of São Paulo

Facilities: 8MV Pelletron Tandem Accelerator since 1975



Several beamlines:

- 1. Radioactive Ion Beams in Brasil (RIBRAS)**
- 2. Large multipurpose scattering chamber**
- 3. Special beam line for applications**
- 4. Enge Split-Pole magnetic spectrometer**
- 5. HPGe array with miniball for particle detection- SACI-PERERE**

Open Laboratory of Nuclear Physics (LAFN)

- About 60-70 users, including staff members, pos-docs, graduate students and external users.
- Project Advisory Committee (PAC)
- Basic nuclear physics activities: mainly nuclear reactions with stable or radioactive projectiles
- Applications: Irradiation of electronic devices
- Techniques for cultural heritage study and collaboration with Brazilian museums

RIBRAS - Radioactive Ion Beams in Brasil

First RIB facility in the Southern Hemisphere, installed in 2004

Two superconducting solenoids: radioactive ion beam production : ${}^6\text{He}$, ${}^8\text{Li}$, ${}^7\text{Be}$, ${}^8\text{B}$, ${}^{10}\text{Be}$, ${}^{17}\text{F}$
Typical intensities: 10^4 - 10^6 pps



Prevision of up-grades at RIBRAS:

The use of **new gamma detectors (LYSO) insensitive to neutrons and to magnetic fields**, which are present close to the solenoids.

This will open new possibilities in reaction measurements.

The use of the **Neutron Wall**, a large position sensitive neutron detector with an obsolete electronics. The purchase of new electronics will put the Neutron wall in excellent conditions. Neutron-charged particle detection in coincidence to exclusive break-up measurements of radioactive nuclei (${}^6\text{He}$, ${}^8\text{Li}$, ${}^{10}\text{Be}$ etc)

Scientific program at RIBRAS

Past and Present

Elastic scattering:

(only first solenoid)

$\left\{ \begin{array}{l} {}^6\text{He} + {}^9\text{Be}, {}^{27}\text{Al}, {}^{51}\text{V}, {}^{58}\text{Ni}, {}^{120}\text{Sn} \\ {}^7\text{Be} + {}^{27}\text{Al}, {}^{51}\text{V} \\ {}^8\text{Li} + {}^{51}\text{V}, {}^8\text{B} + {}^{27}\text{Al} \\ {}^8\text{Li}, {}^{7,9,10}\text{Be} \text{ on } {}^{12}\text{C} \\ {}^8\text{Li} + {}^9\text{Be}, {}^{58}\text{Ni}, {}^{120}\text{Sn} \end{array} \right.$

Present and future

(two solenoids) \longrightarrow

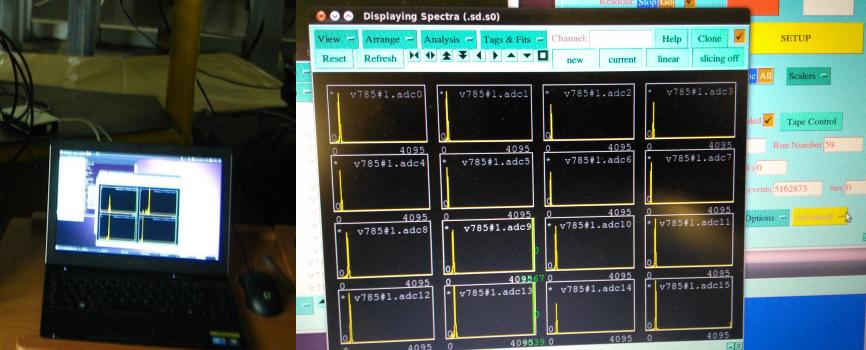
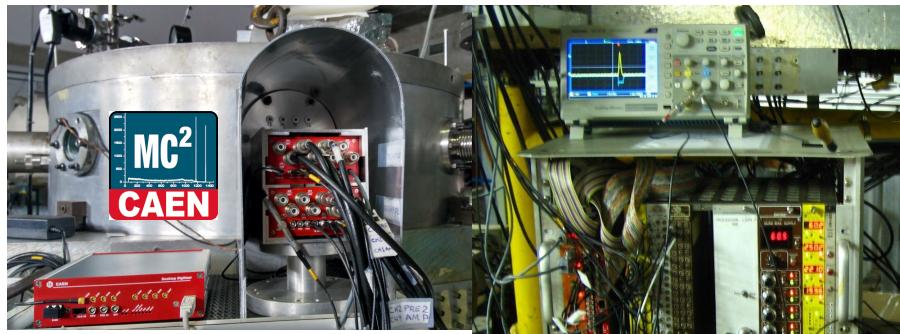
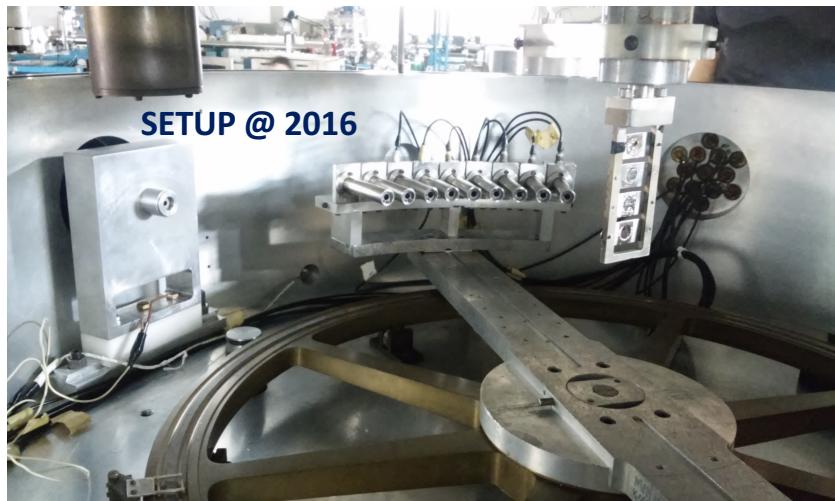
Transfer reactions: ${}^8\text{Li} + p, {}^6\text{He} + p$
 ${}^8\text{Li}(p,\alpha){}^5\text{He}, {}^8\text{Li}(p,d){}^7\text{Li}, {}^8\text{Li}(p,p){}^8\text{Li},$
 ${}^7\text{Be} ({}^9\text{Be}, {}^7\text{Be}) {}^9\text{Be}$

Break-up reactions

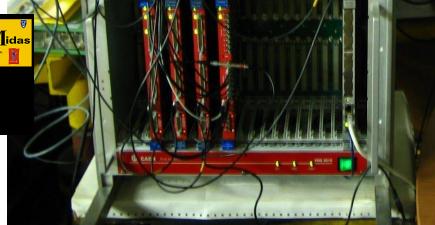
Inelastic scattering

Fusion reactions

GRIPe - multipurpose scattering chamber 30B

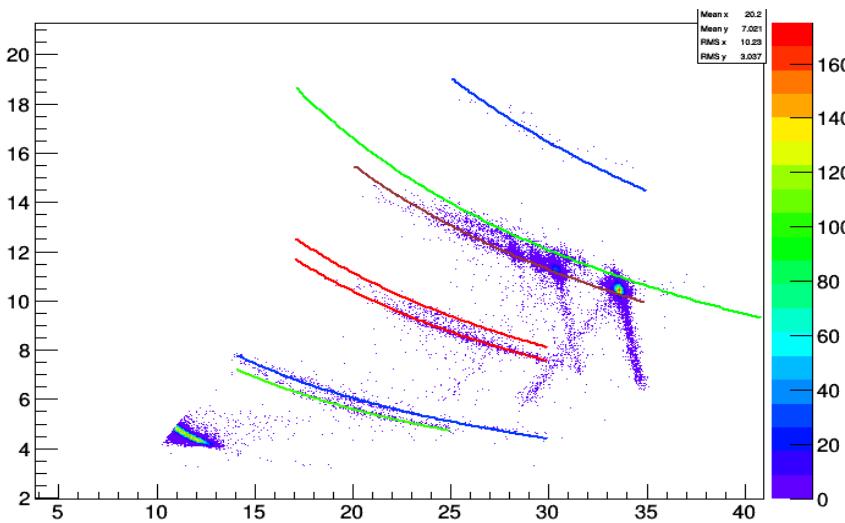
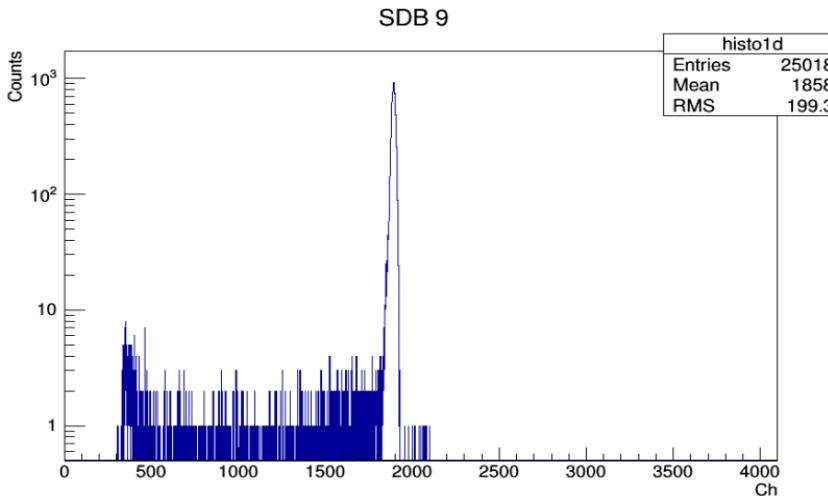
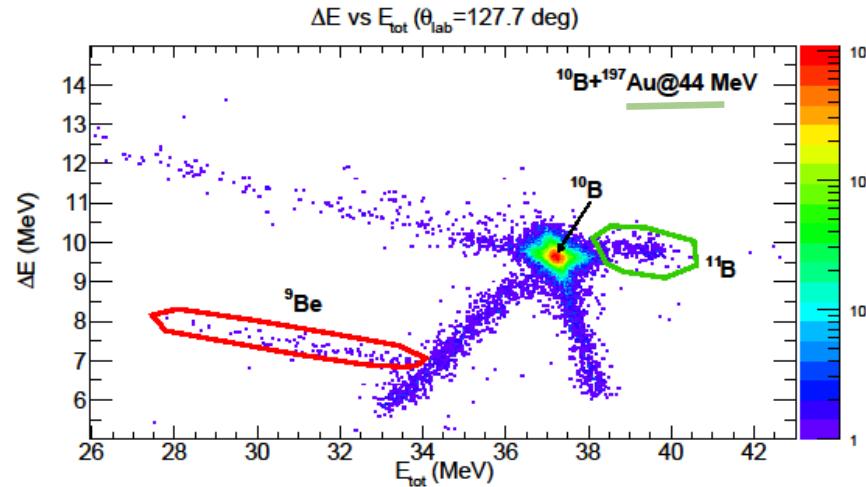
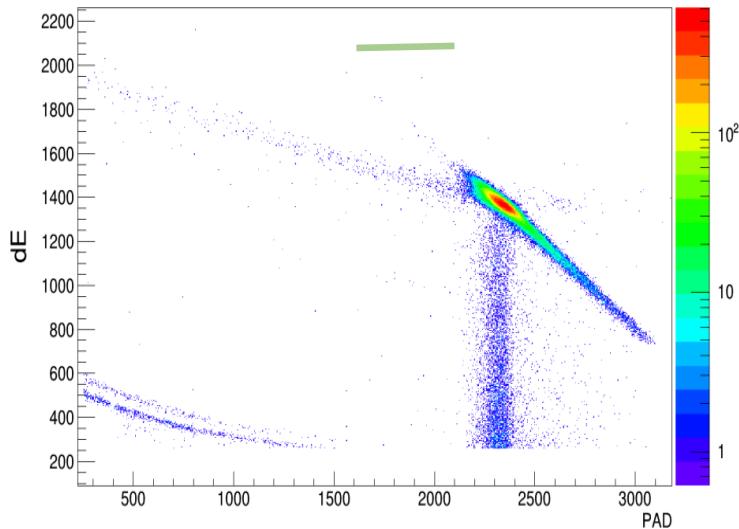


Welcome to **MIDAS**
the
Multi **I**nstance **D**ata **A**cquisition **S**ystem



Recent results – experimental campaingn involving weakly bound projectiles

$^{10}\text{B}+^{197}\text{Au}$ @37.5 MeV (strip 8)



Nuclear Spectroscopy with Light Ions Group

Instituto de Física da Universidade de São Paulo

Thereza Borello Lewin

Márcia Regina Dias Rodrigues

José Luciano Miranda Duarte

Hideaki Miyake

Lighia Brighitta Horodynksi Matsushigue

XinXin Zhang

COLLABORATOR

Cleber Lima Rodrigues (IFUSP)



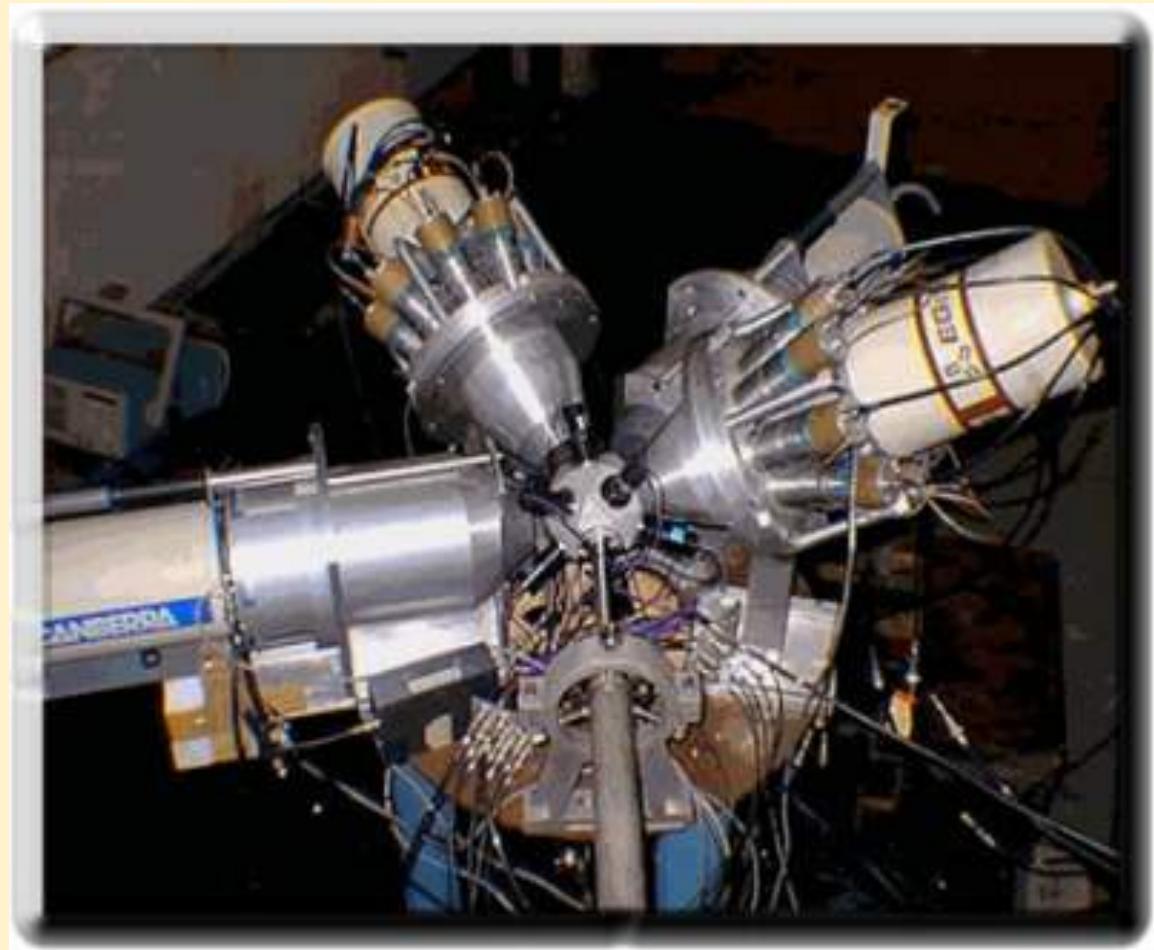
Maximum field	17 kG
Solid angle	2,68 msr
E_{\max}/E_{\min}	7.3
$E/\Delta E$	~ 2750

- Inelastic scattering of 28.0 MeV ${}^6\text{Li}$ exciting the first quadrupole state in ${}^{70,72,74,76}\text{Ge}$
- No $B(\text{IS}2)$ values had been previously reported.

Gamma-ray spectroscopy group

IFUSP

Jose Roberto Brandão de
Oliveira
Nilberto Heder Medina
Roberto V. Ribas
Way
Vinicius Zagatto



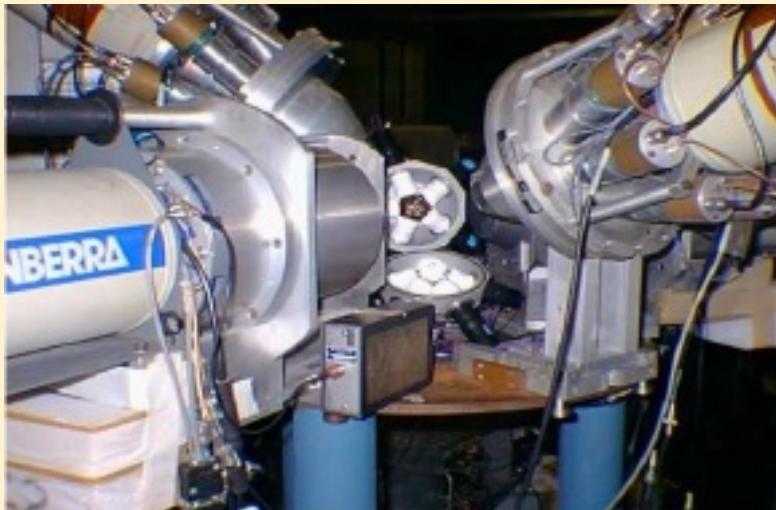
Sistema Ancilar de Cintiladores-Pequeno Espectrometro de Radiação Eletromagnética com Rejeição de Espalhamento - **SACI-PERERE**

Figure of
Brazilian
Folklore



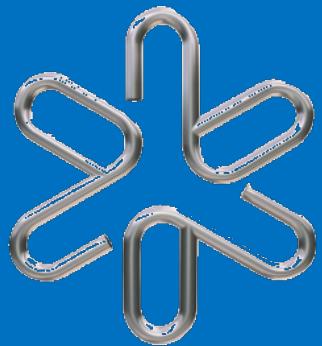
4 HpGe detectors (2og 60% 2 of 20%) with
BGO Compton suppressors.

Mini-ball of 11 $\Delta E-E$ plastic phoswich
scintillator (76% of 4π) particle detectors



Use of the Pelletron Accelerator for Applications

Radiation Effects in Electronic Devices



N.Added

N. H. Medina

V.A.P. Aguiar



Instituto de Física da Universidade de São Paulo

SAFIIRA SYSTEM

SistemA de Feixes Iônicos para IRradiações e Aplicações



All the Electronic Devices May Suffer from Radiation Effects

Space Environment

Ground High Radiation Environment

**Particle and electromagnetic radiation
Ionizing and non-ionizing dose**

Degradation of:

**Micro-electronics, micro-processors,
solar cells, optical components, semiconductor detectors,
front-end electronics, cabling, etc**

Causing: System shutdowns

Circuit damage

Data corruption, etc

**Human beings can also be influenced by radiation effects: astronauts,
airplane crew, passengers, patients, personnel, etc.**

Single Event Effects

Charge generation

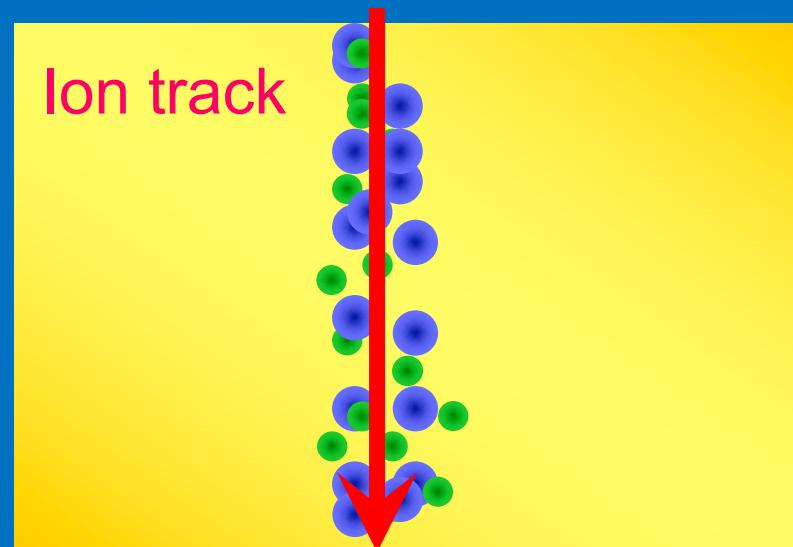
- An ionizing particle generates a track of electron-hole pairs in semiconductors (Silicon) and dielectrics (SiO_2)
- The number of generated carriers is proportional to the particle **Linear Energy Transfer (LET)** ($\text{MeV}/\text{mg}/\text{cm}^2$)

(Energy / e-h pair: **3.6 eV in Si, 17 eV in SiO_2**)

Units: 1 rad = 100 erg/g

1 Gy = 1 J/kg = 100 rad

hole ●
electron ●



Nondestructive Effects

Single event upset (SEU)

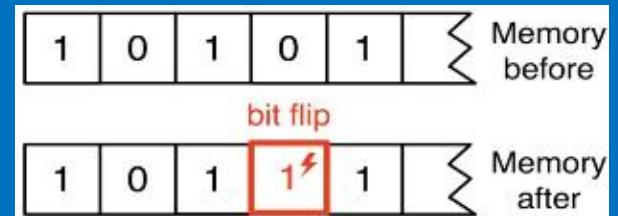
e.g. memory bit-flip (logic error)

Single event transient (SET)

A transient effect (voltage/current pulses) which may provoke a SEU

Single event functional interrupt (SEFI)

Logical malfunction in programmable devices



Destructive Effects

Single event latch-up (SEL)

high current flux overheated power transistors,
affecting e.g. CMOS devices

Single event gate rupture (SEGR)

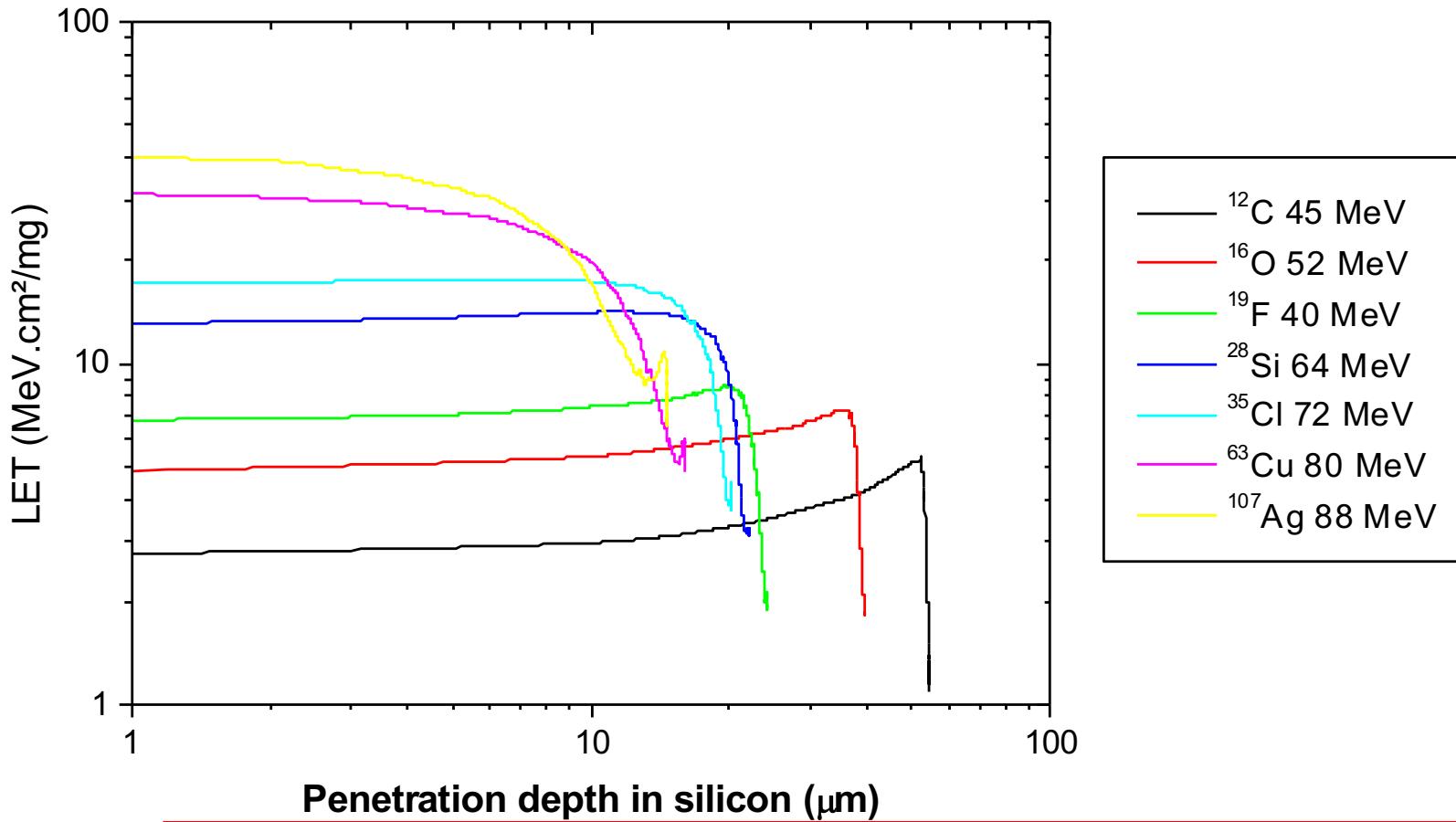
dielectric breakdown of the oxide layer of a MOSFET

Single event burnout (SEB)

Similar to SEL. The high current damage irreversibly ,
e.g. power MOSFET

Linear Energy Transfer (LET)

Energy per depth (1 MeV/mg/cm² ≈ 0.01 pC/μm)



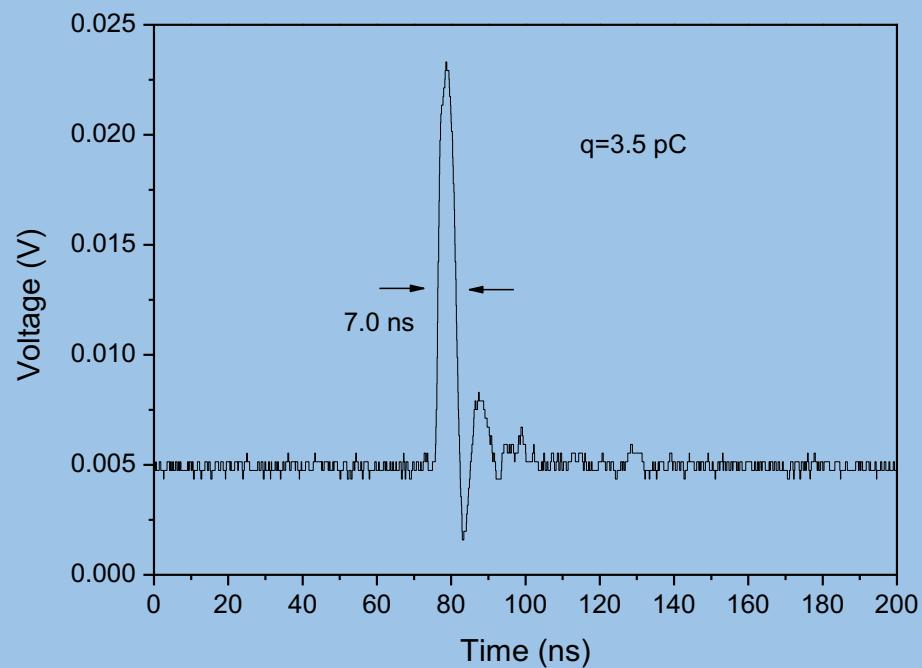
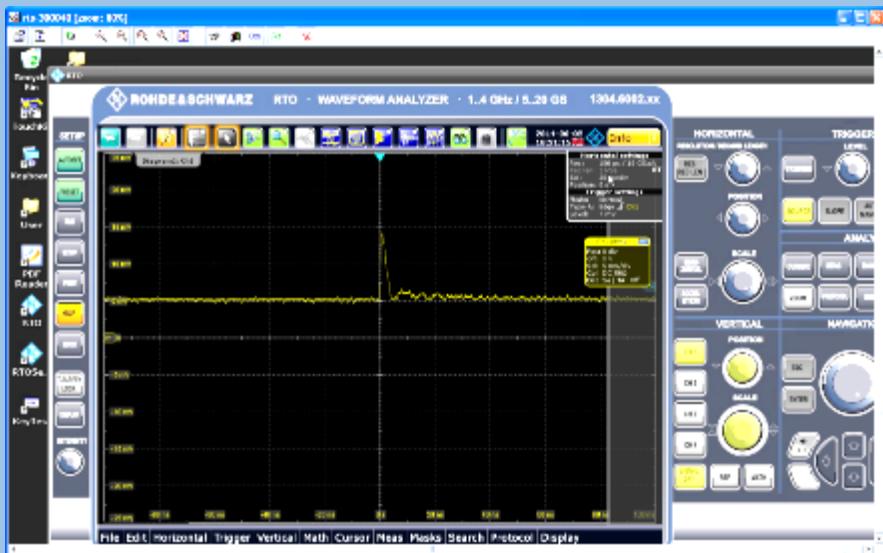
LET as a function of the depth in silicon for the heavy ions available in the 8 UD Pelletron accelerator.

SEU measurements in a p-channel MOSFET transistor (3N163) USP-FEI Collaboration

SEU signal observed with an oscilloscope
due to ^{35}Cl heavy ion beam at 75 MeV.



$$V_G = -0.13 \text{ V}$$
$$V_{DS} = -4.5 \text{ V}$$



Sampling rate 5 Gsamples/s 1-GHz Rohde & Schwarz RTO1012 scope

SUMMARY

We have presented the activities in basic and applied experimental nuclear physics with the Pelletron accelerator.

Nowadays we do not have well defined groups, people are collaborating in different projects, involving stable and radioactive beams.

We still have an active research program, with several students, external users and international collaborations